

ISG56525

5 TO 65 MHz SILICON CATV 25 dB HYBRID AMPLIFIER



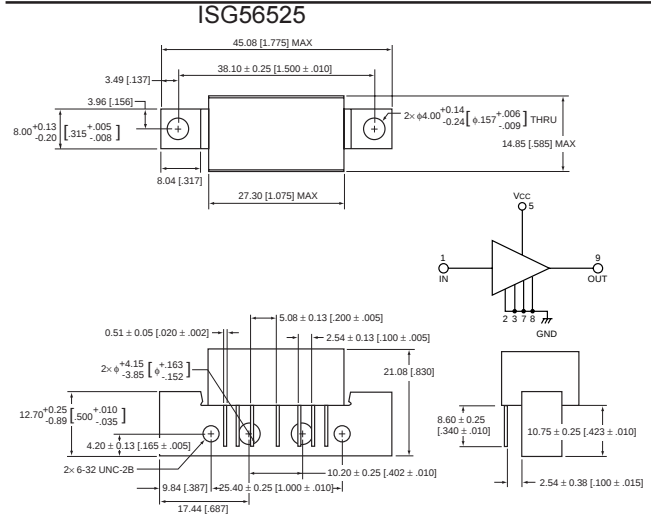
FEATURES

- FLAT GAIN RESPONSE FROM 5 TO 65 MHz: $f = \pm 0.2$ dB
- INPUT AND OUTPUT MATCHING TO 75 OHMS: $R_L = \Rightarrow 19$ dB
- LOW DISTORTION: $P_{1dB} = 78$ dBmV
- LOW NOISE: 3.1dB
- AUTOMATED SURFACE MOUNT CONSTRUCTION

DESCRIPTION

The ISG56525 is a low noise, low distortion hybrid amplifier specified for use in return path HFC Cable TV applications. The ISG56525 is comprised of 100% surface mount components, including high performance silicon transistors. It features excellent noise, gain, and thermal stability across a wide range of operating conditions and frequencies. The amplifiers are manufactured to ISO9002 standards and are very rugged and exhibit excellent unit to unit uniformity.

OUTLINE DIMENSIONS (Units in mm [inches])



ELECTRICAL CHARACTERISTICS ($V_{CC} = 24$ V, $\pm 10\%$ $T_A = 25^\circ\text{C}$, 75 Ω System)

PART NUMBER				ISG56525		
SYMBOLS	PARAMETERS	CONDITIONS	UNITS	MIN	TYP	MAX
GA	Gain		dB	24.5	25.2	26
ΔG	Gain Flatness		dB			± 0.15
R_{LIN}	Input Return Loss		dB	20	25	
R_{LOUT}	Output Return Loss		dB	19	21	
NF	Noise Figure		dB		3.1	3.5
CTB	Composite triple beat	See Note 1	dBc		-64	-60
XM	Cross Modulation (+50 dBmV/CH)	See Note 1	dBc		-54	-51
CSO	2nd Order Intermodulation Product	See Note 1	dBc		-70	-65
P_{1dB}	Output Power at 1dB Gain Compression point		dBmV	75	76	
V_{CC}	Supply Voltage		V		24	
I_{OP}	Operating Current		mA	105	117	130
BW	Bandwidth		MHz	5		65
Ω	Input & Output Impedance		ohms		75	

Note:

1. Composite Triple Beat, Cross Modulation, 2nd Order Distortion are all measured with 7 channels (T7 through T13) at 50 dBmV/ch output and at 25°C.

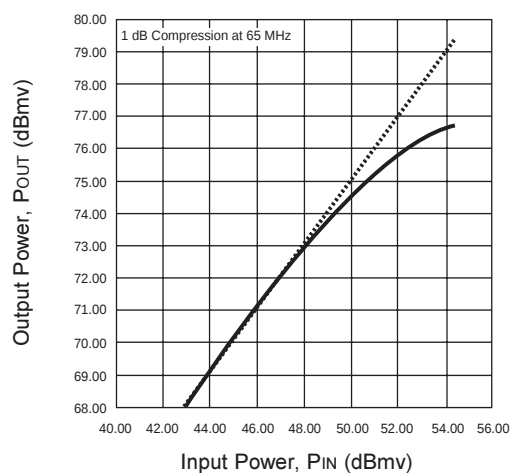
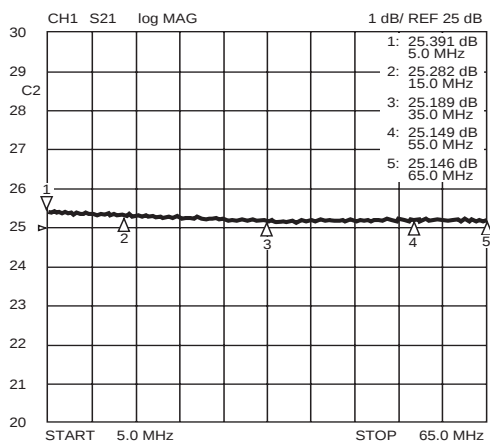
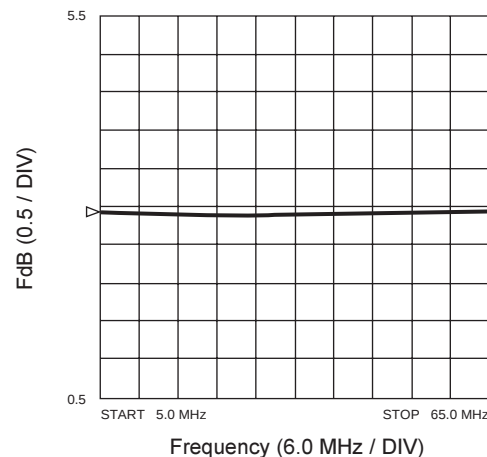
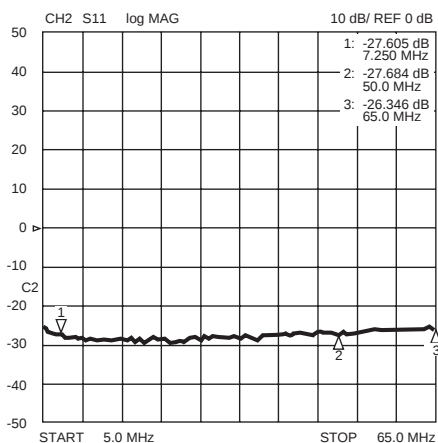
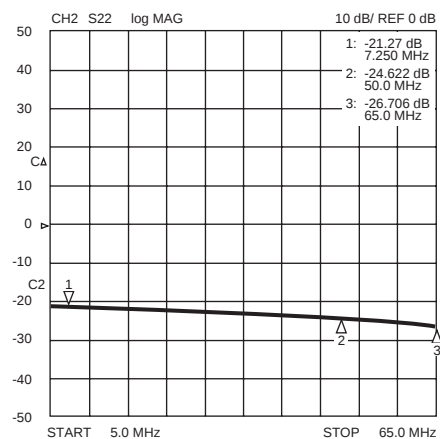
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ABSOLUTE MAXIMUM RATINGS¹(T_C = 25 °C unless otherwise noted)

SYMBOLS	PARAMETERS	UNITS	RATINGS
V _{CC}	DC Supply	V _{DC}	+28
V _{IN}	RF Input Voltage (Single Tone)	dBmV	+70
T _C	Operating Case Temperature Range	°C	-40 to +100
T _{STG}	Storage Temperature Range	°C	-40 to +100

Note:

1. Operation in excess of any one of these parameters may result in permanent damage.

TYPICAL PERFORMANCE CURVES (T_A = 25°C)**power in vs power out @ 65 MHz****GAIN vs. FREQUENCY****NOISE FIGURE****INPUT RETURN LOSS****OUTPUT RETURN LOSS**

DATA SUBJECT TO CHANGE WITHOUT NOTICE